Unit: mm

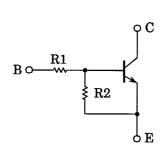
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1201,RN1202,RN1203,RN1204,RN1205,RN1206

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2201~2206

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1201	4.7	4.7
RN1202	10	10
RN1203	22	22
RN1204	47	47
RN1205	2.2	47
RN1206	4.7	47

1. EMITTER 2. COLLECTOR 3. BASE JEDEC EIAJ

2-4E1A

Weight: 0.13g

TOSHIBA

Maximum Ratings (Ta = 25°C)

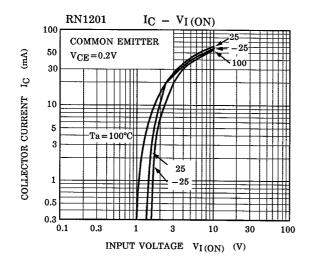
Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN1201~1206	V _{CBO}	50	V	
Collector-emitter voltage	1(11/201 1/200	V _{CEO}	50	V	
Emitter-base voltage	RN1201~1204	V _{EBO}	10	V	
	RN1205, 1206	vEBO.	5		
Collector current		I _c	100	mA	
Collector power dissipation	RN1201~1206	Pc	300	mW	
Junction temperature	KN1201**1200	T _j		°C	
Storage temperature range		T _{stg}	-55~150	°C	

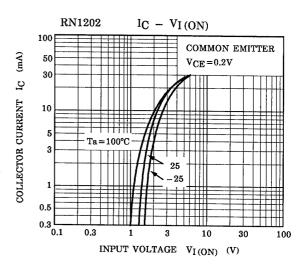


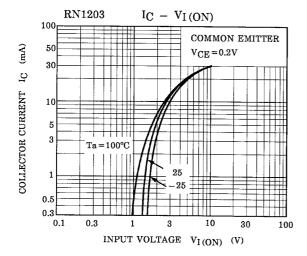
Electrical Characteristics (Ta = 25°C)

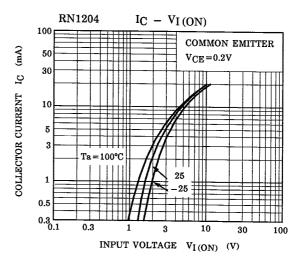
Characteris	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1201~1206	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
	101201-1200	I _{CEO}	_	V _{CE} = 50V, I _B = 0	_	_	500	nA
Emitter cut-off current	RN1201	I _{EBO}	_	V _{EB} = 10V, I _C = 0	0.82	_	1.52	- mA
	RN1202		_		0.38	_	0.71	
	RN1203		_		0.17	_	0.33	
	RN1204		_		0.082	_	0.15	
	RN1205		_	V _{EB} = 5V, I _C = 0	0.078	_	0.145	
	RN1206		_		0.074	_	0.138	
DC current gain	RN1201		_		30	_	_	
	RN1202		_		50	_	_	
	RN1203	h _{FE}	_		70	_	_	
	RN1204		_	V _{CE} = 5V, I _C = 10mA	80	_	_	
	RN1205		_		80	_	_	
	RN1206	-	_	_	80	_	_	
Collector-emitter saturation voltage	RN1201~1206	V _{CE} (sat)	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	٧
Input voltage (ON)	RN1201	V _I (ON)	_	- - - - - - - - - - - - - - - - - - -	1.1	_	2.0	. V
	RN1202		_		1.2	_	2.4	
	RN1203		_		1.3	_	3.0	
	RN1204		_		1.5	_	5.0	
	RN1205		_		0.6	_	1.1	
	RN1206		_		0.7	_	1.3	
Input voltage (OFF)	RN1201~1204	V _{I (OFF)}	_	- V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	V
	RN1205~1206		_		0.5	_	8.0	
Translation frequency	RN1201~1206	f _T	_	V _{CE} =10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance	RN1201~1206	$C_{\sf ob}$	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3	6	pF
Input Resistor	RN1201	R1	_		3.29	4.7	6.11	kΩ
	RN1202		_		7	10	13	
	RN1203		_		15.4	22	28.6	
	RN1204		_		32.9	47	61.1	
	RN1205		_		1.54	2.2	2.86	
	RN1206		_		3.29	4.7	6.11	
Resistor Ratio	RN1201~1205	R1/R2	_		0.9	1.0	1.1	_
	RN1205		_		0.0421	0.0468	0.0515	
	RN1206		_		0.09	0.1	0.11	

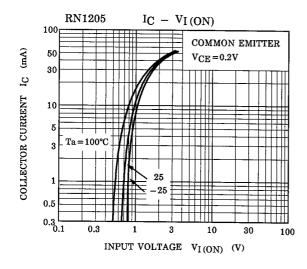
2

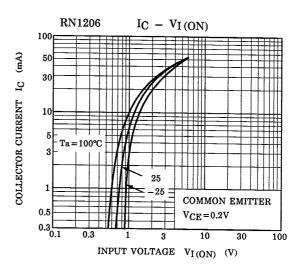


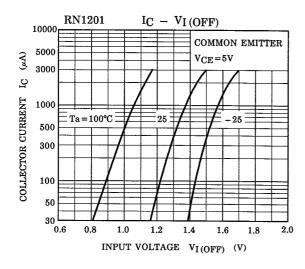


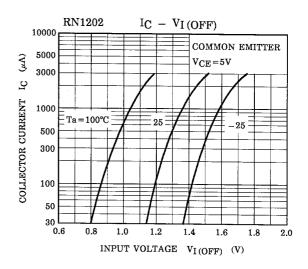


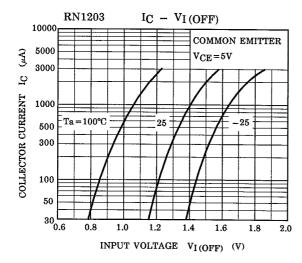


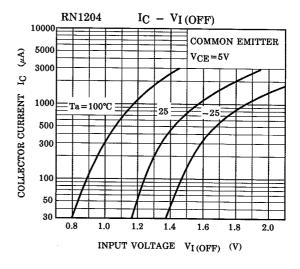


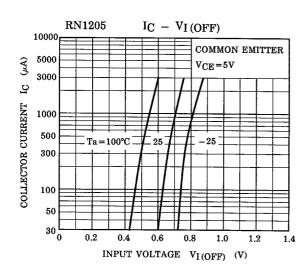


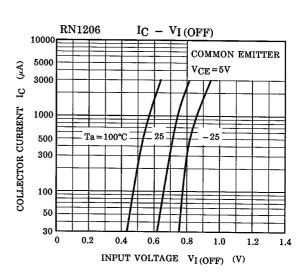


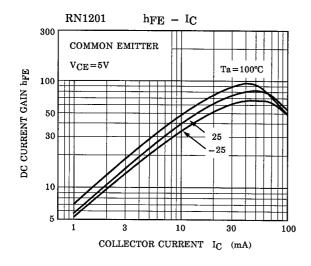


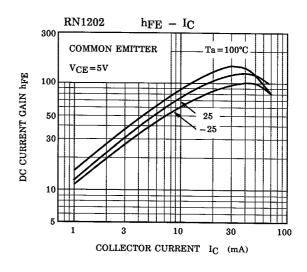


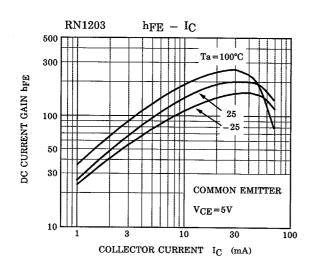


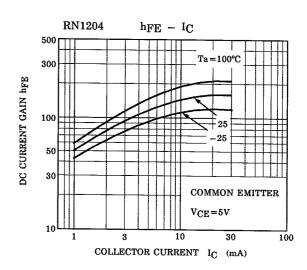


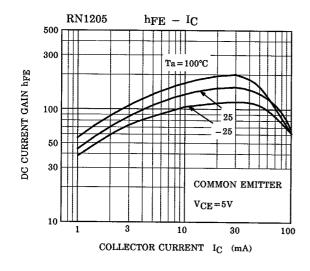


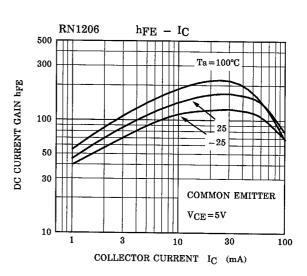












RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.